

H5N2522LS

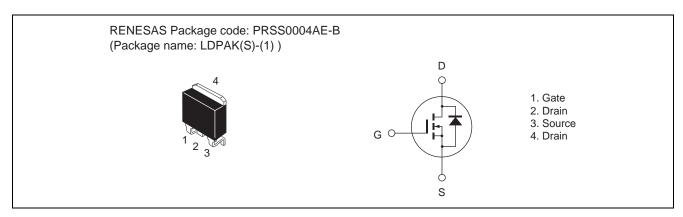
Silicon N Channel MOS FET High Speed Power Switching

R07DS0057EJ0200 (Previous: REJ03G1667-0100) Rev.2.00 Jul 23, 2010

Features

- Low on-resistance $R_{DS(on)}=0.14~\Omega~typ.~(at~I_D=10~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- Low leakage current
- High speed switching
- Built-in fast recovery diode

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	250	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I _D	20	А
Drain peak current	I _{D (pulse)} Note1	60	А
Body-drain diode reverse drain current	I _{DR}	20	А
Body-drain diode reverse drain peak current	I _{DR (pulse)} Note1	60	А
Avalanche current	I _{AP} Note3	20	А
Avalanche energy	E _{AR} Note3	25	mJ
Channel dissipation	Pch Note2	75	W
Channel to case thermal impedance	θch-c	1.67	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at $Tc = 25^{\circ}C$
- 3. STch = 25° C, Tch $\leq 150^{\circ}$ C

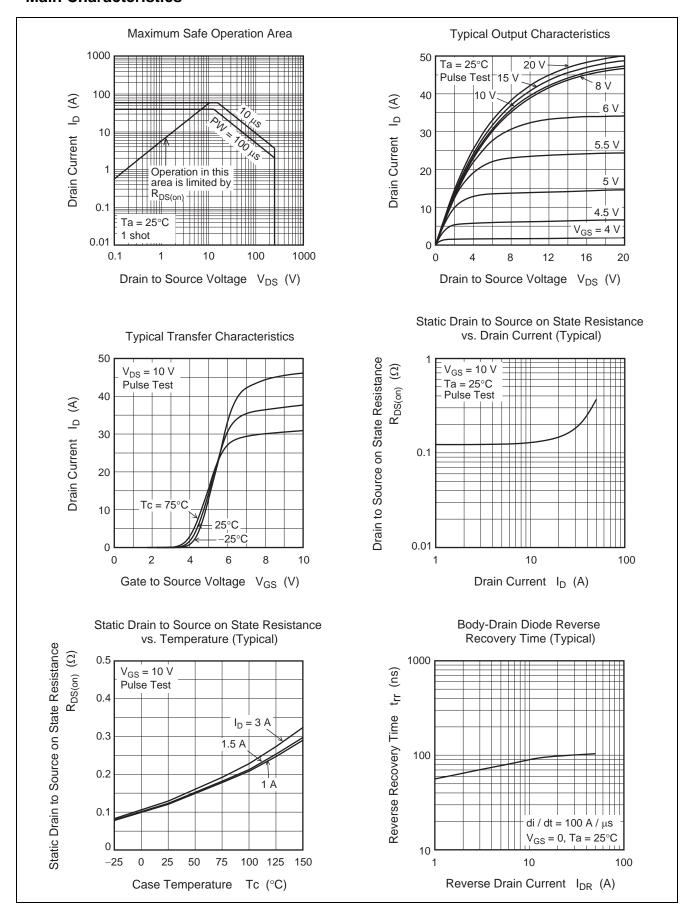
Electrical Characteristics

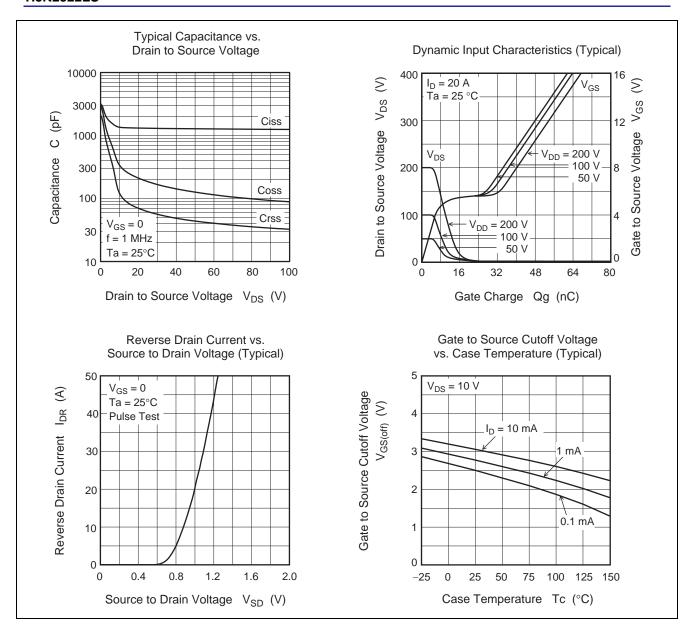
 $(Ta = 25^{\circ}C)$

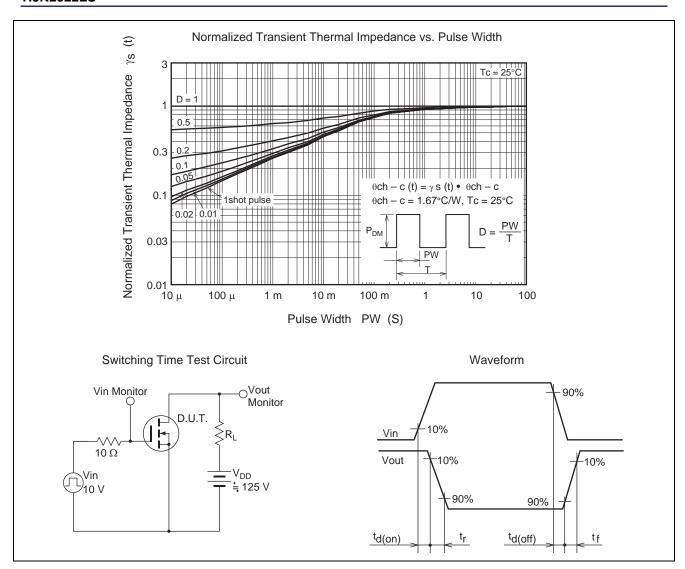
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	250	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 250 \text{ V}, V_{GS} = 0$
Gate to source leak current	I _{GSS}	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS(off)}	1.5	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state resistance	R _{DS(on)}	_	0.14	0.18	Ω	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	1300	_	pF	V _{DS} = 25 V
Output capacitance	Coss	_	185	_	pF	V _{GS} = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	62	_	pF	
Turn-on delay time	t _{d(on)}	_	27	_	ns	I _D = 10 A
Rise time	t _r	_	41	_	ns	$V_{GS} = 10 \text{ V}$ $R_L = 12.5 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t _{d(off)}	_	88	_	ns	
Fall time	t _f	_	16	_	ns	
Total gate charge	Qg	_	47	_	nC	V _{DD} = 200 V
Gate to source charge	Qgs	_	7	_	nC	V _{GS} = 10 V I _D = 20 A
Gate to drain charge	Qgd	_	24.5	_	nC	
Body-drain diode forward voltage	V_{DF}	_	0.99	1.54	V	$I_F = 20 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery time	t _{rr}	_	120	_	ns	$I_F = 20 \text{ A}, V_{GS} = 0$ $di_F/dt = 100 \text{ A}/\mu \text{s}$

Notes: 4. Pulse test

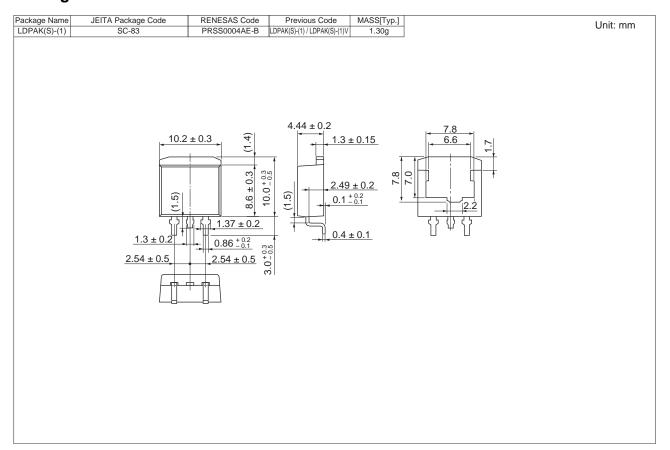
Main Characteristics







Package Dimensions



Ordering Information

Part No.	Quantity	Shipping Container
H5N2522LSTL-E	1000 pcs	Taping

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